

Form PTO 1449 (Modified)		U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE		ATTY DOCKET NO. 278285US0PCT		SERIAL NO. 10/549,364	
LIST OF REFERENCES CITED BY APPLICANT				APPLICANT Makoto ISHIDA, et al.			
				FILING DATE July 17, 2006		GROUP 2826	
U.S. PATENT DOCUMENTS							
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE
		AA					
		AB					
		AG					
		AD					
		AE					
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FOREIGN PATENT DOCUMENTS							
		DOCUMENT NUMBER	DATE	COUNTRY	TRANSLATION YES NO		
		AO					
		AP					
		AO					
		AR					
		AS					
		AT					
		AU					
		AV					
OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, etc.)							
	AW	D. AKAI ET AL, Science d Direct, "Epitaxial Growth of Pt(001) thin films on Si substrates using an epitaxial γ -Al ₂ O ₃ (001) buffer layer, Journal of Crystal Growth 264 (2004) 463-467					
	AX	D. AKAI, APPLIED PHYSICS LETTERS 86, 202906 (2005), Ferroelectric properties of sol-gel delivered epitaxial Pb(Zr _x , Ti _{1-x})O ₃ THIN FILMS ON SI USING EPITAXIAL γ -Al ₂ O ₃ Layers					
	AY						
	AZ					<input type="checkbox"/> Additional References sheet(s) attached	
Examiner /Kevin Quinto/					Date Considered 04/11/2008		
*Examiner: Initial if reference is considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.							